

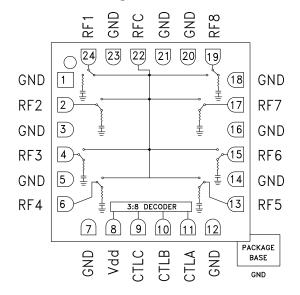


#### **Typical Applications**

The HMC253LC4 is ideal for:

- Basestations & Repeaters
- WiMAX/WiBro & Fixed Wireless
- Cellular/3G Infrastructure
- CATV/DBS
- Military & Hi-Rel

#### **Functional Diagram**



# GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

#### Features

Ceramic, RoHS Compliant 4x4mm SMT Package Non-Reflective Topology Low Insertion Loss: 1.2 dB Single Positive Supply: Vdd = +5V Integrated 3:8 TTL/CMOS Decoder: 0/+3V

#### **General Description**

The HMC253LC4 is a non-reflective SP8T switch in a leadless RoHS compliant 4x4 mm ceramic SMT package featuring wideband operation from DC to 3.5 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility enabling it to operate with 0/+3V control and a +5V supply. A 3:8 decoder is integrated on the switch requiring only 3 control lines and a positive bias to select each path. The HMC253LC4 SP8T will replace multiple configurations of SP4T and SPDT MMIC switches.

#### **Electrical Specifications**, $T_{A} = +25^{\circ}$ C, For TTL Control and Vdd = +5V in a 50 Ohm system

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 3.0 GHz DC - 3.5 GHz		1.1 1.2 1.3	1.5 1.6 1.7	dB dB dB
Isolation		DC - 2.0 GHz DC - 3.0 GHz DC - 3.5 GHz	35 31 30	40 36 35		dB dB dB
Return Loss	"On State"	0.3 - 3.0 GHz 0.3 - 3.5 GHz	15 12	18 14		dB dB
Return Loss (RF1-8)	"Off State"	0.3 - 3.5 GHz 0.5 - 3.5 GHz	7 10	10 14		dB dB
Input Power for 1 dB Compression		0.5 - 3.5 GHz	20	24		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 3.5 GHz	40	43		dBm
Switching Characteristics		0.3 - 3.5 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)				30 100		ns ns

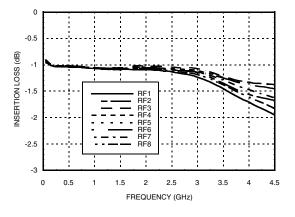
For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com



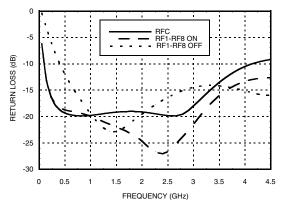


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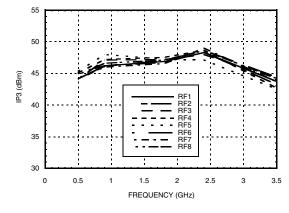
#### **Insertion Loss**



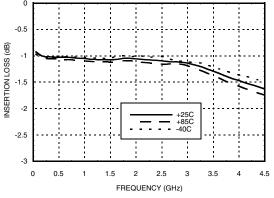
#### **Return Loss**



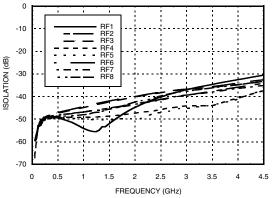
#### Input IP3



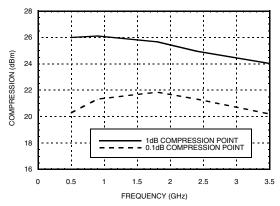
#### Insertion Loss vs. Temperature



#### Isolation



#### Input Compression



SWITCHES - MULTI-THROW - SMT

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# GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

#### **Bias Voltage & Current**

Vdd Range = +5 Vdc ± 10%			
Vdd (Vdc) Idd (Typ.) (mA) Idd (Max.) (mA)			
+5	6.0	9.0	

#### **TTL/CMOS Control Voltages**

State Bias Condition		Bias Condition
	Low	0 to +0.8 Vdc @ 5 μA Typ.
	High	+2.0 to +5 Vdc @ 70 μA Typ.

### Truth Table

	Control Input	Signal Path State	
А	В	С	RFCOM to:
Low	Low	Low	RF1
High	Low	Low	RF2
Low	High	Low	RF3
High	High	Low	RF4
Low	Low	High	RF5
High	Low	High	RF6
Low	High	High	RF7
High	High	High	RF8

#### NOTE:

DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4, 5, 6, 7, 8.

### Absolute Maximum Ratings

Bias Voltage Range (Port Vdd)	+7.0 Vdc
Control Voltage Range (A, B, C)	-0.5V to Vdd +1Vdc
Channel Temperature	150 °C
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5V	+20 dBm (0.05 - 0.5 GHz) +25 dBm (0.5 - 3.5 GHz)



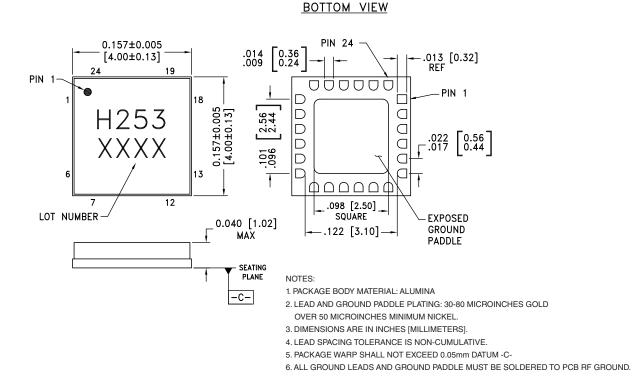
ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS



### GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz



#### **Outline Drawing**



#### **Package Information**

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC253LC4	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H253 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX





# GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

#### **Pin Descriptions**

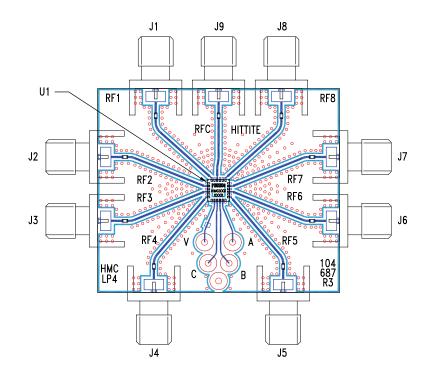
Pin Number	Function	Description	Interface Schematic
1, 3, 5, 7, 12, 14, 16, 18, 20, 21, 23	GND	Package bottom has exposed metal paddle that must also be connected to RF ground.	
2, 4, 6, 13, 15, 17, 19, 22, 24	RF1 - RF8 & RFC	This pin is DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
8	Vdd	Supply Voltage +5 Vdc ±10%	VddO
9	CTLC		∑ <sup>⊙ Vdd</sup>
10	CTLB	See truth table and control voltage table.	
11	CTLA		





### GaAs MMIC SP8T NON-REFLECTIVE SWITCH, DC - 3.5 GHz

#### **Evaluation Circuit Board**



#### List of Materials for Evaluation PCB 107780 [1]

Item	Description
J1 - J9	PCB Mount SMA Connector
J10 - J14	DC Pin
C1 - C9	100 pF Capacitor, 0402 Pkg.
C10	0.01 uF Capacitor, 0603 Pkg.
U1	HMC253LC4 SP8T Switch
PCB <sup>[2]</sup>	104687 Eval Board

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown above. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

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